

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
-30V	7mΩ @ V _{GS} = -10V	-90A
	16mΩ @ V _{GS} = -4.5V	-60A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power-management functions
- DC-DC converters

Features and Benefits

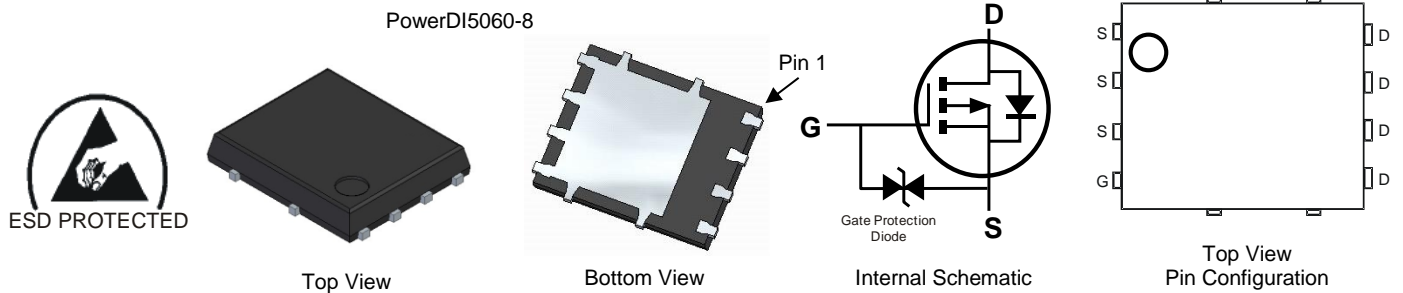
- Low R_{DS(ON)} – Minimizes On-State Losses
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- 100% Unclamped Inductive Switching, Test in Production – Ensures More Reliable and Robust End Application
- ESD Protected Gate
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. “Green” Device (Note 3)**
- **The DMP3007SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

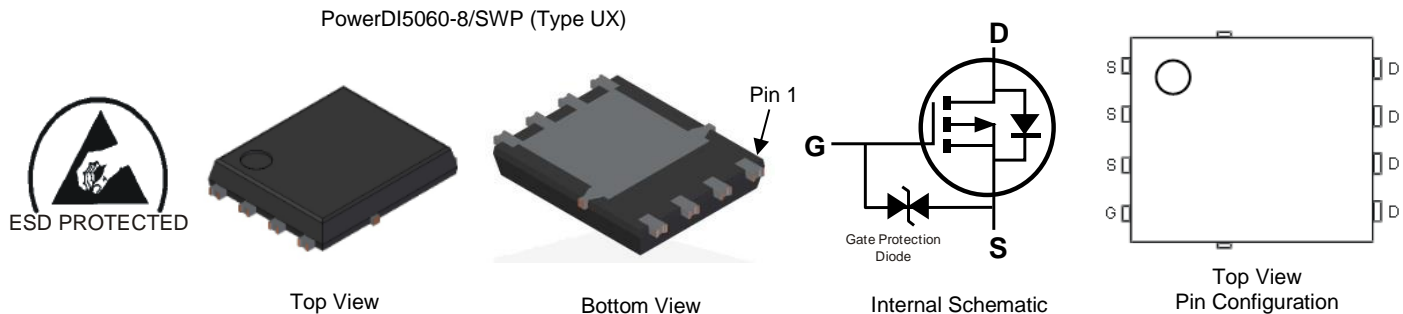
Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.097 grams (Approximate)

Site 1:



Site 2:



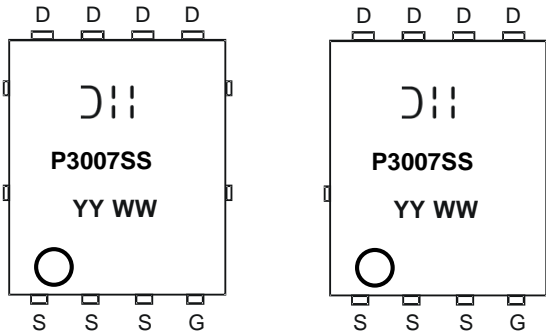
- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
DMP3007SPSQ-13	PowerDI5060-8	2,500	Tape & Reel
	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel

Note: 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



D||| = Manufacturer's Marking
 P3007SS = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Year (ex: 23 = 2023)
 WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	-30	V
Gate-Source Voltage	V _{GSS}	±25	V
Continuous Drain Current, V _{GS} = -10V (Note 5)	I _D	T _C = +25°C	-90
		T _C = +70°C	-70
Maximum Continuous Body Diode Forward Current (Note 5)	I _S	-90	A
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)	I _{DM}	-160	A
Avalanche Current, L = 1mH (Note 6)	I _{AS}	-16	A
Avalanche Energy, L = 1mH (Note 6)	E _{AS}	130	mJ

Thermal Characteristics

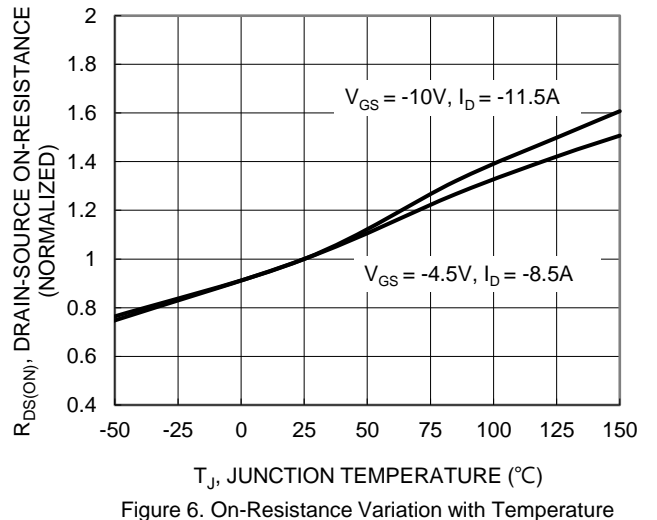
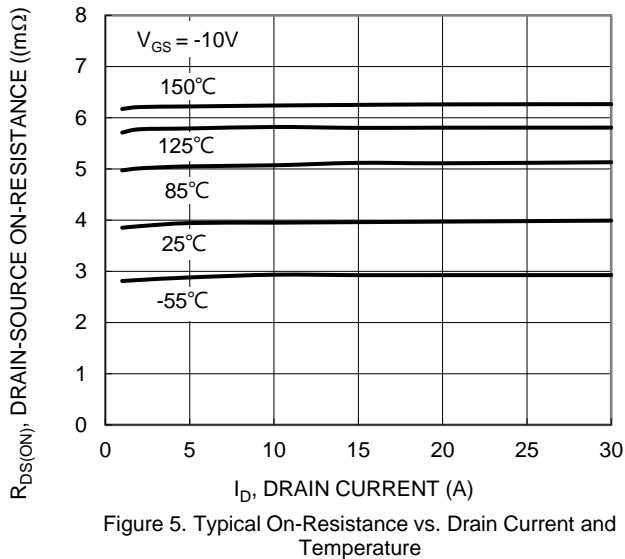
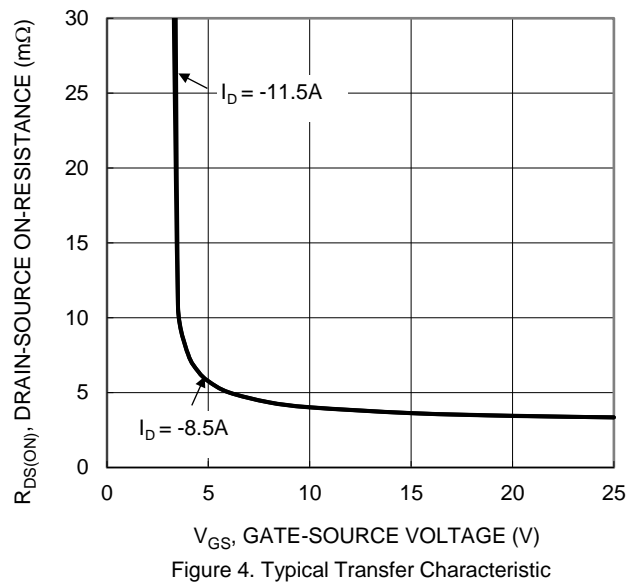
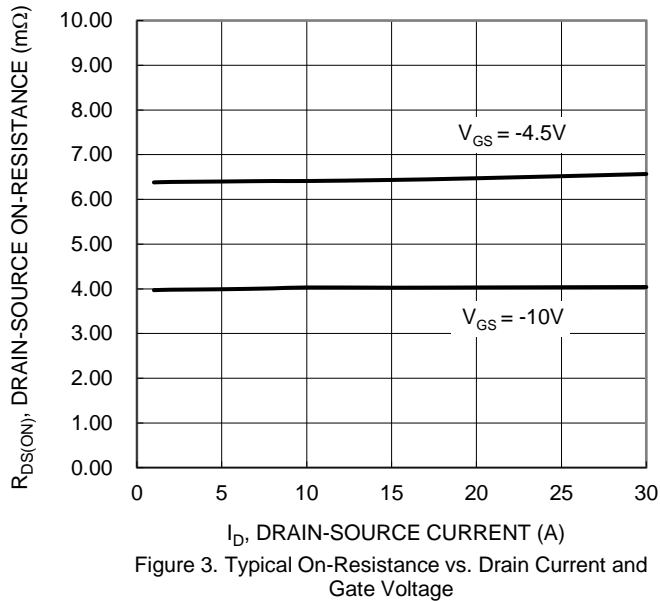
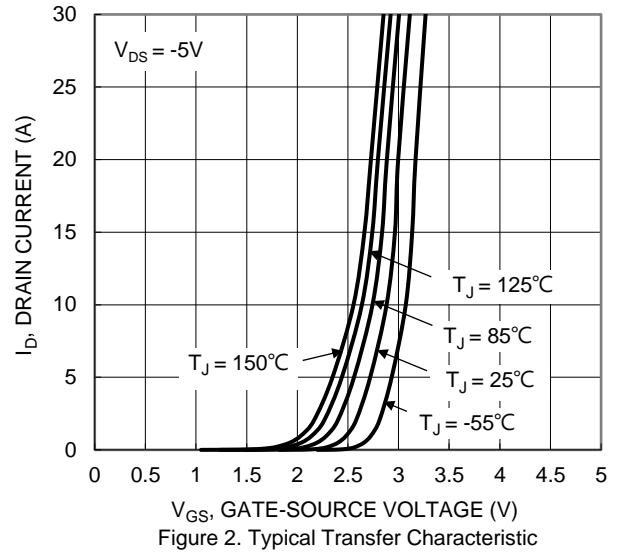
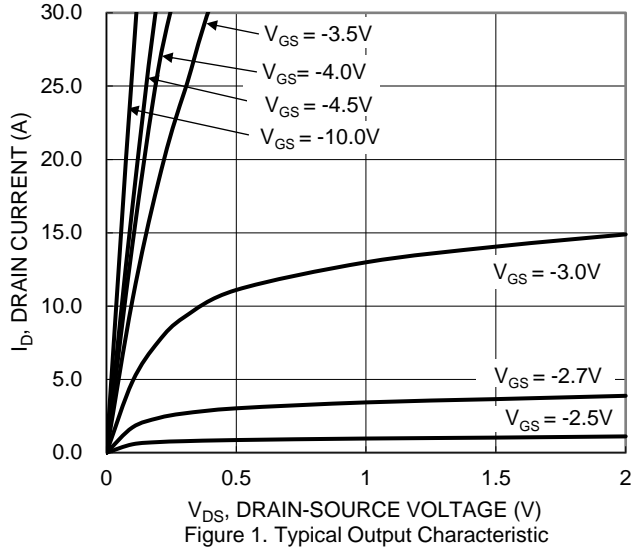
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 7)	P _D	1.4	W
Thermal Resistance, Junction to Ambient (Note 7)	R _{θJA}	90	°C/W
Total Power Dissipation (Note 8)	P _D	2.7	W
Thermal Resistance, Junction to Ambient (Note 8)	R _{θJA}	47	°C/W
Total Power Dissipation (Note 5)	P _D	80	W
Thermal Resistance, Junction to Case (Note 5)	R _{θJC}	1.5	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
5. Thermal resistance from junction to soldering point (on the exposed drain pad).
 6. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
 7. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 8. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

Electrical Characteristics ($T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Drain-Source Breakdown Voltage	BV_{DSS}	-30	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-1	μA	$V_{DS} = -24V, V_{GS} = 0V$
Gate-Source Leakage	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	$V_{GS(TH)}$	-1.0	—	-3.0	V	$V_{DS} = V_{GS}, I_D = -250\mu A$
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	4.5	7	m Ω	$V_{GS} = -10V, I_D = -15A$
		—	12	16		$V_{GS} = -4.5V, I_D = -10A$
Diode Forward Voltage	V_{SD}	—	-0.7	-1.2	V	$V_{GS} = 0V, I_S = -1A$
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	C_{iss}	—	2,826	—	pF	$V_{DS} = -15V, V_{GS} = 0V$ $f = 1.0MHz$
Output Capacitance	C_{oss}	—	606	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	305	—	pF	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Gate Resistance	R_g	—	23	—	Ω	
Total Gate Charge ($V_{GS} = -4.5V$)	Q_g	—	31.2	—	nC	$V_{DS} = -15V, I_D = -11.5A$
Total Gate Charge ($V_{GS} = -10V$)	Q_g	—	64.2	—	nC	
Gate-Source Charge	Q_{gs}	—	10.6	—	nC	
Gate-Drain Charge	Q_{gd}	—	11.6	—	nC	
Turn-On Delay Time	$t_{D(ON)}$	—	4.8	—	ns	
Turn-On Rise Time	t_R	—	4.3	—	ns	$V_{DD} = -15V, V_{GS} = -10V$ $R_g = 6\Omega, I_D = -11.5A$
Turn-Off Delay Time	$t_{D(OFF)}$	—	306	—	ns	
Turn-Off Fall Time	t_F	—	125	—	ns	$I_S = -11.5A, dI/dt = 100A/\mu s$
Reverse Recovery Time	t_{RR}	—	19	—	ns	
Reverse Recovery Charge	Q_{RR}	—	9.8	—	nC	

Notes: 9. Short duration pulse test used to minimize self-heating effect.
10. Guaranteed by design. Not subject to product testing.



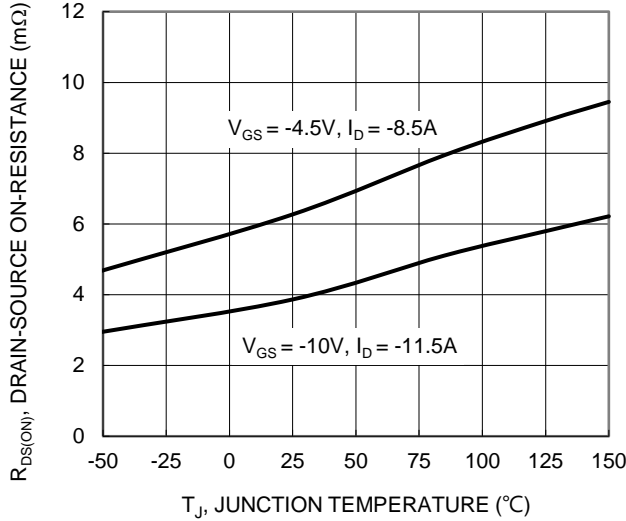


Figure 7. On-Resistance Variation with Temperature

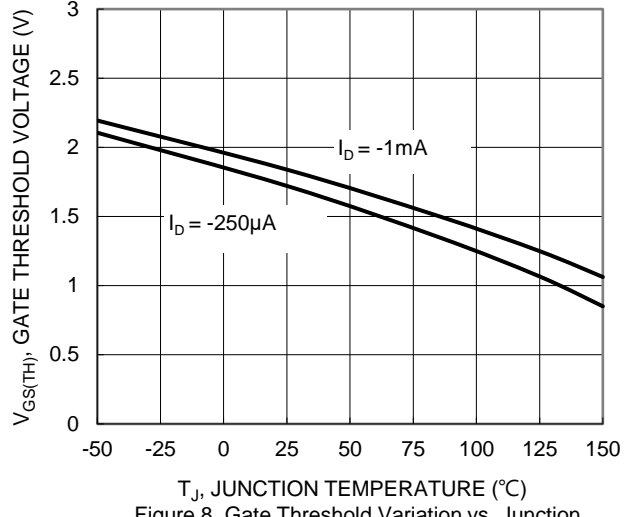


Figure 8. Gate Threshold Variation vs. Junction Temperature

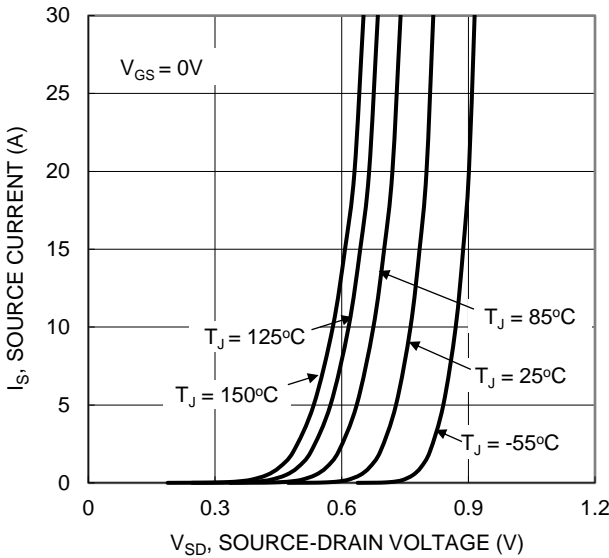


Figure 9. Diode Forward Voltage vs. Current

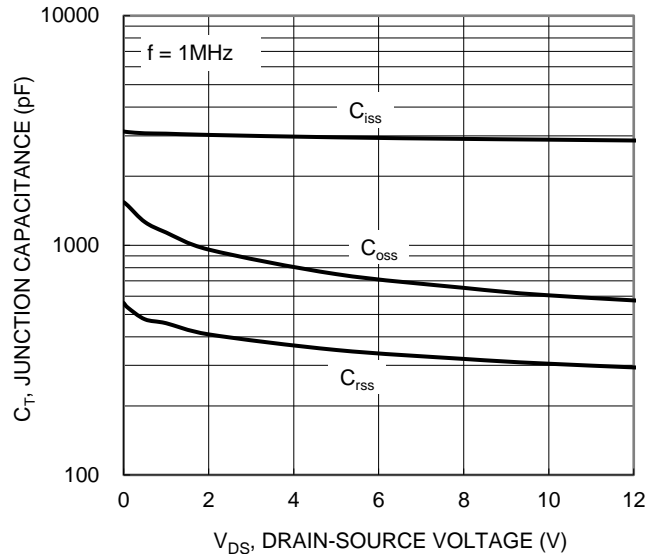


Figure 10. Typical Junction Capacitance

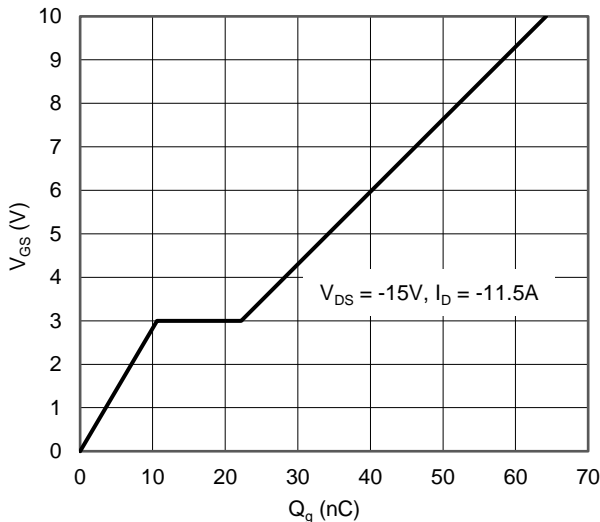


Figure 11. Gate Charge

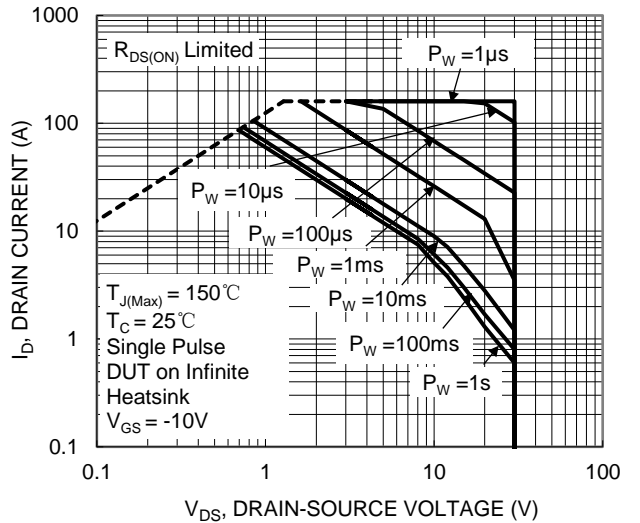


Figure 12. SOA, Safe Operation Area

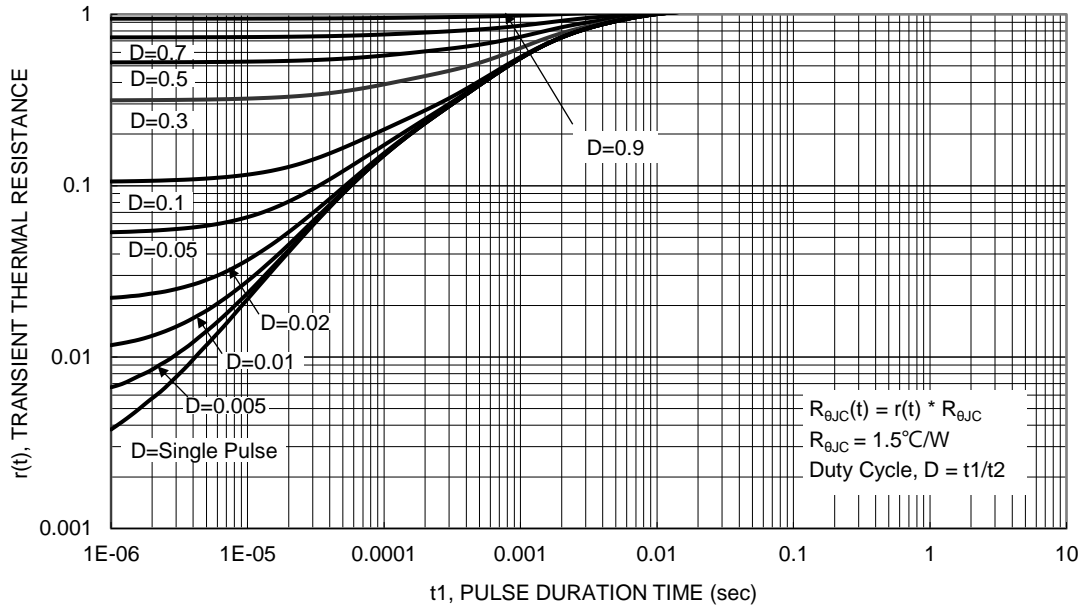


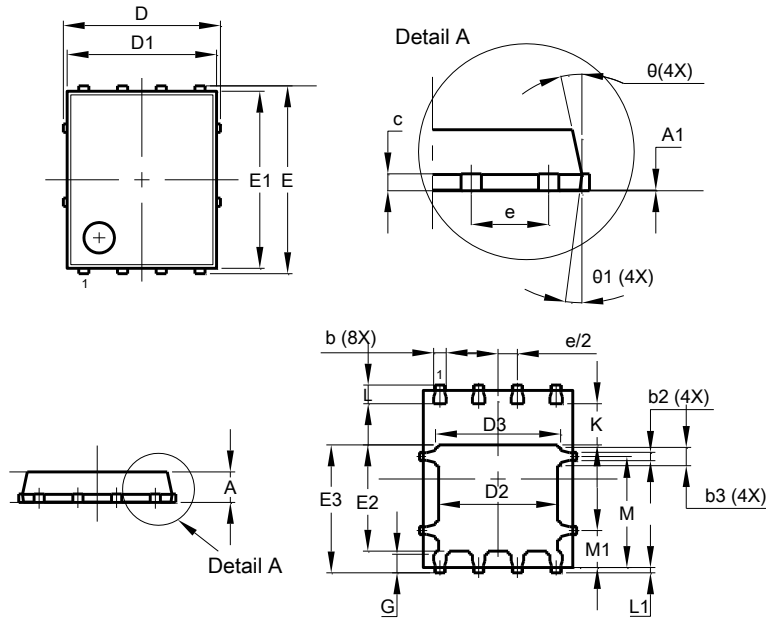
Figure 13. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

Site 1:

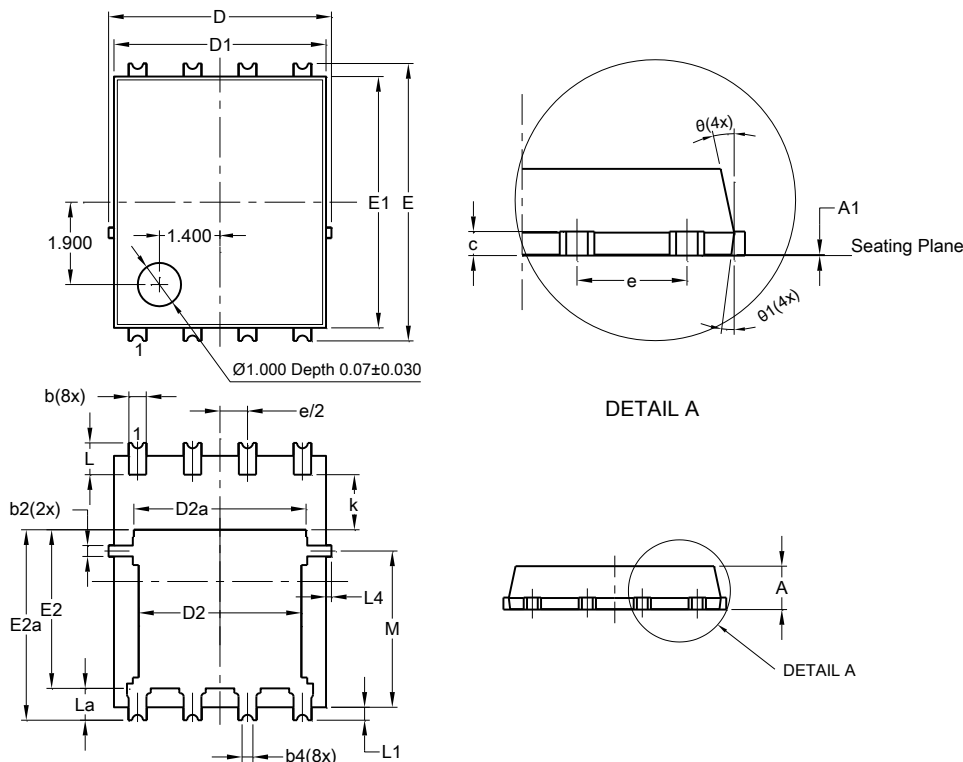
PowerDI5060-8



PowerDI5060-8			
Dim	Min	Max	Typ
A	0.90	1.10	1.00
A1	0.00	0.05	-
b	0.33	0.51	0.41
b2	0.200	0.350	0.273
b3	0.40	0.80	0.60
c	0.230	0.330	0.277
D	5.15 BSC		
D1	4.70	5.10	4.90
D2	3.70	4.10	3.90
D3	3.90	4.30	4.10
E	6.15 BSC		
E1	5.60	6.00	5.80
E2	3.28	3.68	3.48
E3	3.99	4.39	4.19
e	1.27 BSC		
G	0.51	0.71	0.61
K	0.51	-	-
L	0.51	0.71	0.61
L1	0.100	0.200	0.175
M	3.235	4.035	3.635
M1	1.00	1.40	1.21
θ	10°	12°	11°
θ1	6°	8°	7°
All Dimensions in mm			

Site 2:

PowerDI5060-8/SWP (Type UX)



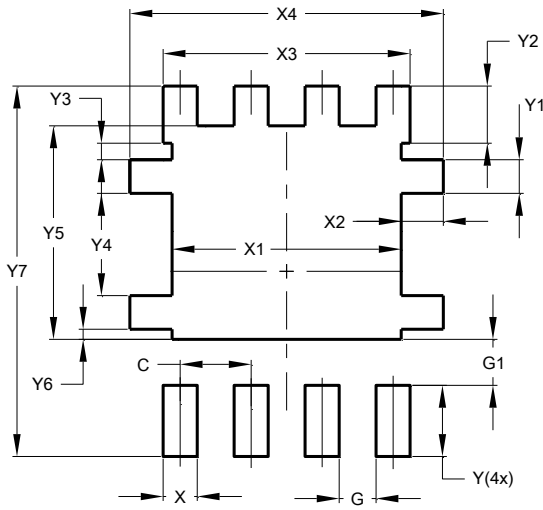
PowerDI5060-8/SWP (Type UX)			
Dim	Min	Max	Typ
A	0.90	1.10	1.00
A1	0	0.05	--
b	0.30	0.50	0.41
b2	0.20	0.35	0.25
b4	0.25REF		
c	0.230	0.330	0.277
D	5.15 BSC		
D1	4.70	5.10	4.90
D2	3.56	3.96	3.76
D2a	3.78	4.18	3.98
E	6.40 BSC		
E1	5.60	6.00	5.80
E2	3.46	3.86	3.66
E2a	4.195	4.595	4.395
e	1.27BSC		
k	1.05	--	--
L	0.635	0.835	0.735
La	0.635	0.835	0.735
L1	0.200	0.400	0.300
L1a	0.050REF		
L4	0.025	0.225	0.125
M	3.205	4.005	3.605
θ	10°	12°	11°
θ1	6°	8°	7°
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

Site 1:

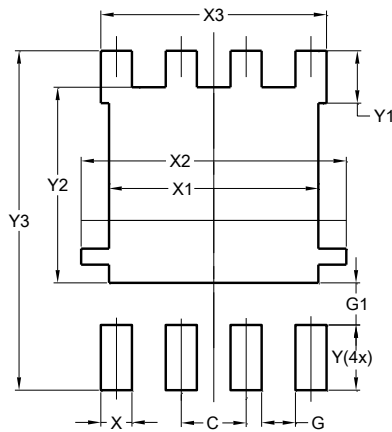
PowerDI5060-8



Dimensions	Value (in mm)
C	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)
C	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	5.190
X3	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610

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